

Electrical conductivity of oxidized-graphenic nanoplatelets obtained from bamboo: Effect of the oxygen content

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Abstract

Large-scale production of graphene and reduced-graphene oxide (rGO) requires low-cost and eco-friendly synthesis methods. We employed a new, simple, cost-effective pyrolytic method to synthesize oxidized-graphenic nanoplatelets (OGNP) using bamboo pyrolytic acid (BPA) as source. Thorough analyses via high-resolution transmission electron microscopy and electron energy-loss spectroscopy provides a complete structural and chemical description at the local scale of these samples. In particular, we found that at the highest carbonization temperature the OGNP-BPA are mainly in sp^2 bonding configuration (sp^2 fraction of 87%). To determine the electrical properties of single nanoplatelets, these were contacted by Pt nanowires deposited through focused-ion-beam-induced deposition techniques. Increased conductivity by two orders of magnitude is observed as oxygen content decreases from 17 to 5%, reaching a value of 2.3×10^3 S/m at the lowest oxygen content. Temperature-dependent conductivity reveals a semiconductor transport behavior, described by the Mott three-dimensional variable range hopping mechanism. From the localization length, we estimate a band-gap value of 0.2(2) eV for an oxygen content of 5%. This investigation demonstrates the great potential of the OGNP-BPA for technological applications, given that their structural and electrical behavior is similar to the highly-reduced rGO sheets obtained by more sophisticated conventional synthesis methods.

1. Introduction

Graphene oxide (GO) and reduced GO (rGO) have attracted research attention because of their interesting tunable properties, as well as their use as precursors for mass production of graphene sheets [1-9]. Tunability, in combination with the superior properties intrinsic of graphene, makes rGO promising candidate for next-generation nanoelectronic devices. Graphene oxide can be described as an oxidized form of graphene, decorated mostly by hydroxyl and epoxy functional groups distributed randomly along the hexagonal network of carbon atoms and, additionally, by carboxyl groups positioned at the sheet edges [10-14]. Nevertheless, for the case of oxygen content below 25%, it has been predicted that only hydroxyl species can be present [12]. By nature, GO is electrically insulating and, thus, cannot be used without further processing as a conductive nanomaterial. However, it has been shown that reduction of GO is an effective method to obtain metallic or semiconductor structures [4, 15-18]. Reduction of GO is typically carried out through chemical reduction [3, 5, 19], thermal annealing [14, 18, 20], or a combination of both [21]. However, a considerable number of structural defects are concomitantly created during these processes having strong implications on the nature of electrical transport in these materials. Transition from insulator to conducting state via chemical/thermal reduction to derive pure graphene from GO for large-scale production is still not a trivial issue. Long reaction times, multiple steps, and toxicity of the chemical agents are some barriers that still need to be solved.

It is known that C-O bonds present in GO modify the atomic structure of pristine graphene. A comprehensive analysis of the atomic structure of GO and rGO is considered an important step to understand the electronic transport of this material. First principles calculations [22] have shown that by changing the oxidation level and the relative compositions of the epoxy and hydroxyl groups, moderate bandgaps can be opened. Several theoretical models of atomic structure have been also proposed in the literature, such as the Hoffmann model [23], Lorf-Klinowski model [24], Scholz-Boehm model [25], Nakajima-Matsuo model [26], Ruess model [27], Zsabo-Dekany model [28]. On the other hand, experimental high-resolution transmission electron microscopy (HRTEM) investigations have helped to elucidate the distribution of the oxygen-functional groups as well as the kind of structural- and topological defects [29-33]. Nevertheless, until now the exact atomic structure of GO and rGO is still unresolved. In general, recent reports describe GO sheets as a random distribution of oxidized regions bearing the oxygenated functional groups, coexisting with non-oxidized regions wherein most of the carbon atoms preserve sp^2 hybridization.

Electrical conductivity and oxygen concentration are strongly correlated in rGO. In general, it has been shown that by increasing the reduction level of rGO, *i.e.*, by restoring sp^2 hybridization, room temperature conductivity tends to increase [15, 17, 18, 34]. In rGO, electrical conduction is caused by sp^2 hybridization due to the presence of delocalized electrons (π orbital), which freely move throughout the graphitic structure. In oxygenized areas containing a high amount of carbon domains showing sp^3 hybridization, this material behaves as insulator. Charge transport mechanism in a landscape of coexisting sp^2/sp^3 regions is akin to that of disordered semiconductors where electron localization and hopping conduction play a significant role. In fact, depending on oxygen content, rGO-based materials

undergo insulator-semiconductor-semimetal transitions with reduction. Studies varying the sp^2 fraction have shown that diverse types of conduction mechanisms can take place depending on whether the rGO sheet is lightly or highly reduced [43, 47]. Specifically, Eda *et al.*, [43] report two different mechanisms describing the conductivity for low-range and high-range sp^2 -fraction. While the former is dominated by hopping or tunneling amongst the sp^2 clusters, the latter can be described by percolation process. For electrically conductive systems, *i.e.* highly reduced rGO, graphene-based polymer nanocomposites, percolation theory has been developed to describe the geometrical and temperature dependences of the conductivity [Mutlay and Tudoran]. On the other hand, for systems showing semiconductor behavior [12, 22, 35], Amirhasan Nourbakhsh *et al.*, [36] report bandgap generation as a result of oxygen functionalization of graphene for O/C ratio higher than 11.1%. However, authors in [37] claimed that rGO is expected to have a metallic-like behavior for O/C ratio up to 25%. Until now, consensus has not been reached about the sp^2 fraction at which the transport mechanism changes from metallic- to semiconductor-like behavior; that is, why an experimental study in a range of low oxygen content, lower than 25%, is of great relevance to gain further insight in the electrical behavior in this low-oxygen regime.

Regarding the temperature dependence of the conductivity in rGO exhibiting semiconductor-like transport behavior, different conduction mechanisms have been reported [3, 4, 16, 38-42]. Authors in [43] found that while at a higher temperature regime of well-reduced GO thermally-excited carriers dominate the conduction, the low-temperature regime must be described through a variable-range hopping (VRH) model. The temperature-dependent longitudinal conductivity considering the VRH model can be described by the general form: $\ln\sigma(T) \propto (T_0/T)^{1/d+1}$, where d describes the dimensionality of the system [44]. Thus, $d = 2$ and 3 correspond to the Mott VRH conduction mechanism, which was proposed for 2D and 3D systems, respectively, without considering Coulomb interaction. When Coulomb interaction between initial and final hopping sites exists, Efros and Shklovskii [45] proposed the case of $d = 1$ for the long-range hole-electron interaction at the Fermi level. Finally, $d = 0$ corresponds to the Arrhenius-type for thermal-activated conduction mechanism. It is worth mentioning that the first three possibilities have also been applied for analysis of charge transport mechanisms in non-crystalline materials [46].

Large-scale graphene production obtained via rGO exfoliation is still difficult. Defect formation or intercalated species like water molecules make the complete control of exfoliation a challenge [48]. In general, to avoid sophisticated GO reduction processes and eventual environmental contamination from the reducing agents, simple, green, and cost-effective methods are highly desirable. In a recent work, we reported on a new, simple, cost-effective method for the synthesis of oxidized-graphenic platelets by using bamboo pyrolygneous acid (BPA) as source, showing similar vibrational properties as rGO obtained via conventional chemical methods [49]. The present work seeks to gain insight into the local atomic structure and electrical conductivity behavior of OGNP-BPA, given that research on these kinds of properties is of relevance for evaluating the impact on technological applications of this carbon

material obtained through the new fabrication method using natural bamboo as source. We report the electrical transport characterization of single OGNP-BPA for oxygen content ranging from 5 to 17%. For electrical characterization, single nanoplatelets were contacted by focused-ion-beam-induced deposition of Pt nanowires, allowing the intrinsic resistance to dominate over the contact resistances. Measurements of current-voltage characteristic at room-T and temperature dependent resistivity demonstrate that OGNP-BPA show comparable conductivity values as the conventionally synthesized rGO sheets (referenced above) with values around 2.3×10^3 S/m at room temperature and semiconductor-like behavior with bandgap value up to 0.30 eV for the highest oxygen concentration.

2. Experimental

Oxidized-graphenic nanoplatelets studied in this work were obtained by thermal decomposition method using bamboo pyrolytic acid (BPA) extracted from *Guadua angustifolia* Kunth, macana biotype. BPA was obtained by a first pyrolysis process at 973 K using a pyrolysis system under a controlled nitrogen atmosphere. We, thereafter, used the BPA as precursor for OGNP. For this, a second pyrolysis process using the BPA was carried out at different carbonization temperatures (T_{CA}), with T_{CA} varying from 673 to 973 K. Varying T_{CA} allows modifying the crystal structure and oxygen-containing functional groups present in the samples. When the second carbonization process is completed, oxidized-graphenic material is obtained as macro foam, which then turns into nanoplatelets powders by mechanical grinding with a ceramic hand mortar. A detailed description of the method for obtaining oxidized-graphenic material can be found in a previous work [49].

HRTEM, electron diffraction (ED) and electron energy-loss spectroscopy (EELS) spectra were performed on a FEI Titan Cube microscope operating at 80 kV and equipped with a Cs image corrector and a Gatan Tridiem spectrometer. The EELS experiments were performed at liquid nitrogen temperature to hinder carbon contamination. The probe diameter for EELS acquisition was around 30 nm. Convergence and collection angles were 4.6 and 20 mrad, respectively. The energy resolution, measured as the full width at half maximum of the zero loss peak (ZLP), was 0.8 eV with an energy dispersion of 0.2 eV/pixel and 0.6 eV for a dispersion of 0.05 eV/pixel. The first dispersion was used for elemental quantification and the second one for fine-structure analysis and to determine the sp^2 fraction. The typical acquisition times for core-loss and low-loss spectra were 16 and 0.2 seconds, respectively. Background subtraction for the core-loss spectra was performed by modeling the usual inverse power law function and multiple scattering was then removed by Fourier-ratio deconvolution [50] with the low-loss spectrum obtained for exactly the same region of the sample. Oxygen content was then determined from EELS elemental quantification. The sp^2 ratio was determined by using spectra of a highly ordered pyrolytic graphite sample obtained under the same experimental conditions. The exact procedure is explained elsewhere [51].

Mass density and absolute thickness of the analyzed nanoplatelets were obtained by analyzing the low-loss spectra. For this purpose, the low-loss spectra were deconvoluted by the ZLP by using the

PEELS program [52] and the single-scattering spectra were obtained by following Stephen's procedure [53], which also provided the t/λ ratio (t is the thickness of the analyzed crystal and λ is the inelastic mean free path). For each spectrum, the $(\pi + \sigma)$ volume plasmon was then modelled by the Drude model over the top 75% of the plasmon peak intensity (Figure S1 in Supplementary Information) in order to extract the plasmon energy, E_p . This value was then used in the following relation [54] to determine the mass density and by assuming that carbon contributes to four valence electrons and oxygen contributes to six:

$$\rho = \frac{E_p^2 \times m^* \times \epsilon_0 \times \mu \times (12 + 4X_O)}{\hbar^2 \times e^2 \times (4 + 2X_O)}$$

Where ρ is the mass density, E_p is the plasmon energy, ϵ_0 is the vacuum permittivity, μ is the atomic mass unit, e is the elementary charge, \hbar is the Dirac constant, X_O is the atomic fraction determined from core-loss EELS spectra (and by assuming that $X_C + X_O = 1$), and m^* is the effective electron band mass taken as $m^* = 0.87 m$ [55, 56]. Sample thickness was determined by estimating λ with the modified Iakubovskii formula [54, 57], using mass density and oxygen fraction as inputs and yielding a value of $\lambda = 106 \text{ nm}$. This approach has been shown to yield a reasonable estimation of absolute thickness [58].

We also used energy dispersive X-ray spectroscopy (EDS) in a scanning electron microscope (SEM, see below) to complete the compositional study and check oxygen content (atomic percent, C_O). In order to perform electrical measurements of individual nanoplatelets, the samples were prepared by suspending OGNP-BP in isopropanol and depositing them in proximity to the metallic contact pads (fabricated firstly by optical lithography) on a SiO_2/Si substrate. Individual nanoplatelets were then located at low voltages ($< 5 \text{ kV}$) using a SEM equipped with a focused ion beam (FIB) (Helios 650 model by FEI). The focused ion beam induced deposition (FIBID) technique was used to deposit four Pt lead wires to connect the nanoplatelets to the metallic contact pads where micro-probes were positioned. The Pt-based contacts deposited optimally by FIBID allow low-contact resistivity to perform noise-free electrical characterization of micro- or nanostructures [59, 60]; for more details of this technique please refer to [61]. The SEM images of the experimental setup displaying the micro-probes, the metallic contact pads, and Pt wires on a single OGNP-BPA are shown in figure 1. The electrical measurements were performed by injecting current in a range of $\pm 6 \mu\text{A}$ on the two external contacts using a Keithley 6220 DC current source; while the voltage was measured at the two internal contacts with a Keithley 2182A nanovoltmeter (see the bottom right panel in figure 1). Temperature-dependent measurements of the resistance were performed within a vacuum chamber using a closed-cycle Helium cryostat system.

3. Results and Discussion

3.1 Morphology, structural and chemical investigations

To gain further insight on the structural and chemical properties, HRTEM and EELS analyses were performed on the nanoplatelets. A combination of TEM and EELS is a powerful tool to get access to valuable information with nanometer or sub-Ångström resolution [62-65]. In particular, a wealth of

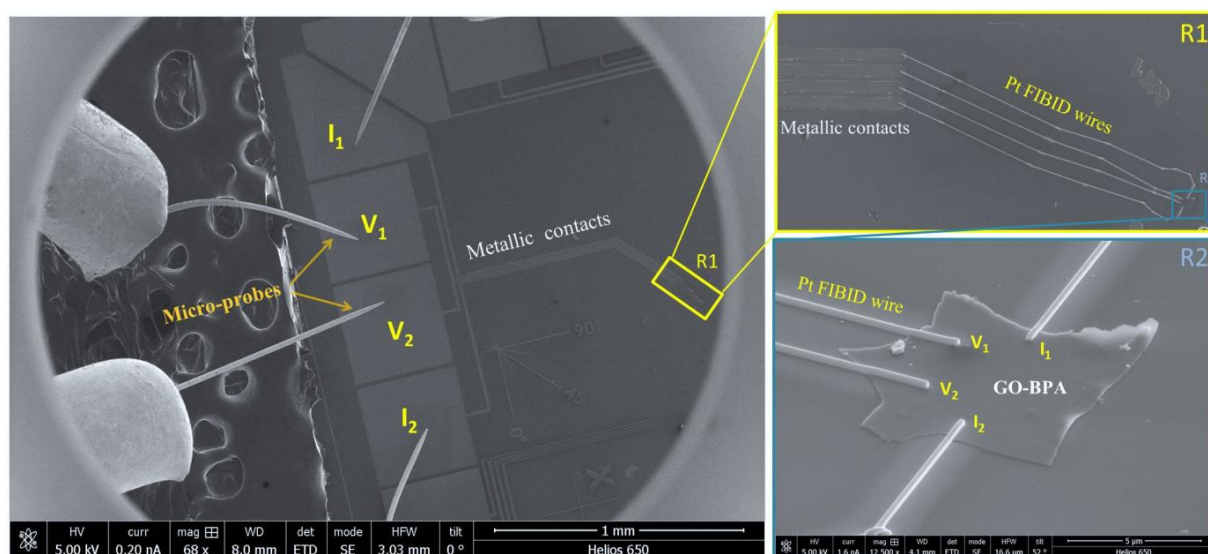


Figure 1. Scanning electron microscopy image of the experimental setup displaying the micro-probes and the metallic contact pads (left), zoomed area of region R1 showing the Pt-wires grown via FIBID technique on a SiO₂/Si substrate (top right), and zoomed area of region R2 showing a typical OGNP-BPA with lateral dimensions around 7 μm and thickness $t < 100$ nm, and Pt contacts to perform the electrical measurements (bottom right).

chemical information related to elemental quantification, mass density, local chemical environment, valence state and bonding hybridization can be extracted from carbon nanostructures and other materials [55, 66, 67]. Figures 2(a) and 2(b) show TEM micrographs of the samples prepared with the highest T_{CA} (973 K) and the lowest one (673 K), respectively. Thin nanoplatelets are clearly visible upon the TEM carbon membrane. Nanoplatelets size is typically in the order of a dozen micrometers and presents a thickness, as estimated from low-loss EELS spectra, ranging between 25 and 60 nm.

Figures 2(c) and 2(d) show two HRTEM micrographs of the samples prepared with a T_{CA} of 973 and 673 K, respectively. The presence of disordered graphitic clusters is clearly highlighted (blue arrows in figure 2(c)) for the sample prepared at T_{CA} of 973 K, while the micrograph of the sample prepared at T_{CA} of 673 K is more characteristic of disordered materials. The selected area electron diffraction (insets of figures 2(a) and 2(b)) show diffuse rings characteristic of disordered and low-order material. The random attachments of the oxygen functional groups on the top and bottom surfaces of OGNP-BPA monolayers play a crucial role in determining the stacking order; because they: *i*) break the symmetry of the subjacent honeycomb carbon lattice; *ii*) introduce a slight roughness, which is originated from out-of-plane lattice distortions of the C-O bonds and *iii*) increase the interlayer spacing (XRD diffractograms in Figure S2 in supplementary information, confirm an increased interlayer spacing with increasing oxygen content). Due to the higher interlayer spacing, individual layers show rotational -and tilt- disorder relative to their neighbors and thus, no preferred stacking orientation. Nevertheless, it is

worth to mention that diffracted rings are better defined for the sample prepared with a T_{CA} of 973 K and, thus, confirm the higher local order of this sample.

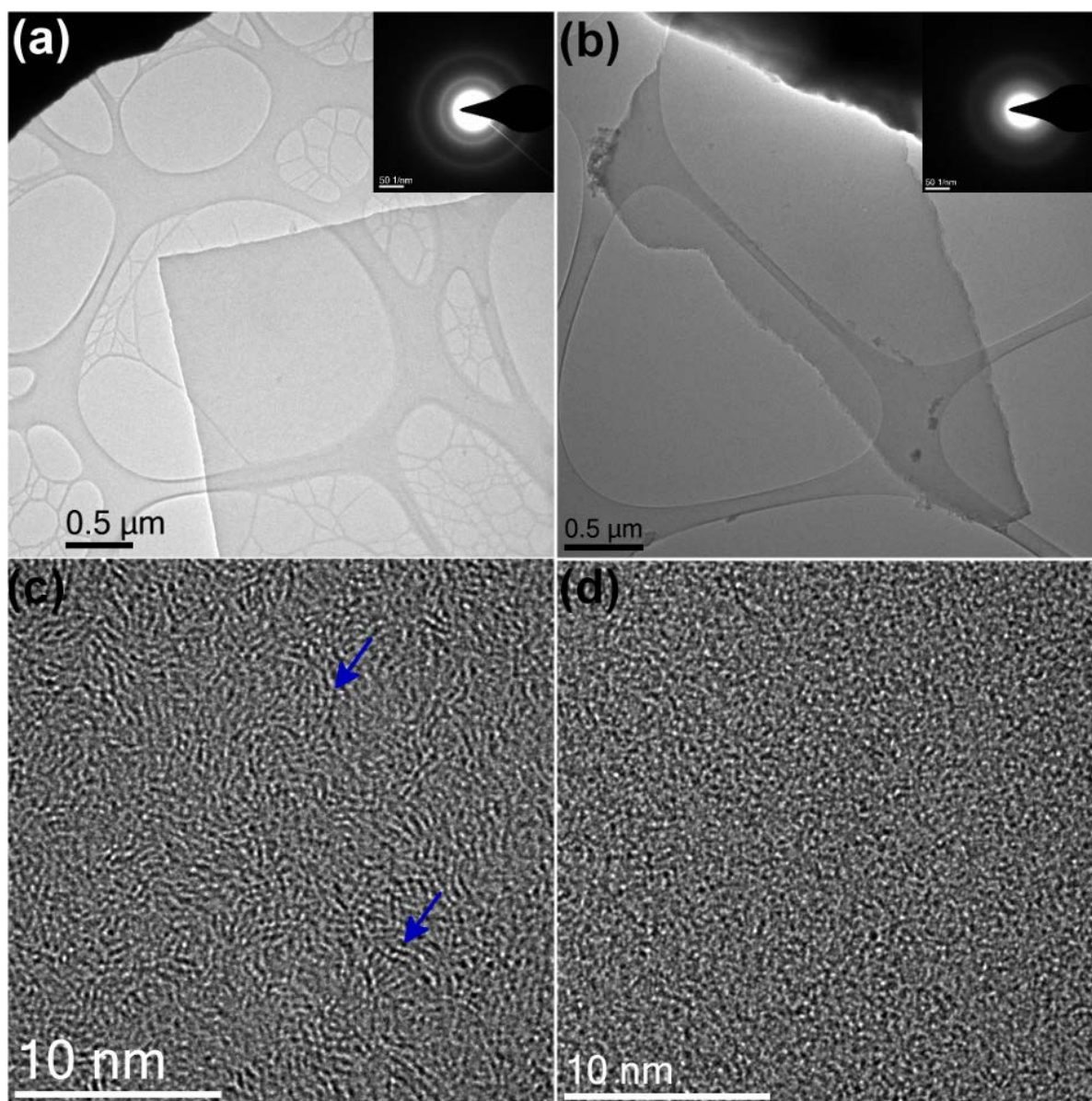


Figure 2. (a) and (b) Low-magnification TEM micrographs of the sample prepared with a T_{CA} of 973 and 673 K, respectively. Insets show the selected area electron diffraction. (c) and (d) HRTEM micrographs of the sample prepared with a T_{CA} of 973 and 673 K, respectively. The blue arrows highlight the disordered graphitic clusters.

Despite the short range crystal order and the incoherence along the c-direction due the high interlayer spacing values, accurate EELS measurements gave evidence about the high level of sp²-bonds in our nanoplatelets. Figure 3(a) shows the EELS spectra of the samples prepared at 973 and 673 K. The C-K edge (roughly situated between 280 and 325 eV) and the O-K edge (situated around 530 eV) are clearly visible. In addition, a change of the slope around 400 eV (highlighted by a red

arrow in figure 3(a)) indicates the presence of nitrogen at chemical trace level. The XPS analyses performed on the whole powders confirmed the presence of nitrogen with a concentration below 1% for all the samples. The O/(C+O) ratio determined by EELS is around 3% and 12% for the samples prepared at 973 and 673 K, respectively, although it is important to bear in mind that precise and accurate EELS quantification requires comparison with reference materials [67]. Figure 3(b) shows the C-K edge of the two samples with a higher resolution. Between 290 and 305 eV, the spectrum of the sample prepared at 973 K presents characteristic graphite-like fine structures (blue arrows in figure 3(b)), indicating the influence of band-structure effect. This is of importance because it confirms the presence of a short-range crystalline order and shows that locally the carbon is mainly in threefold (sp^2) bonding configuration. In the same energy range, the C-K edge of the sample prepared at 673 K is featureless and similar to the spectra of amorphous carbons [51, 68]. At 286.7 eV, the spectrum of the sample prepared at 673 K show a supplementary peak (green arrow in figure 3(b)), which could be linked to the presence of oxygen. For instance, C=O bonds give rise to transitions to π^* states in the energy range between 287.7 and 288.3 eV and C-H bonds give rise to transitions to σ^* states in the energy range between 287.6 and 288.2 eV [69, 70]. However, the determination of the origin of this supplementary transition based solely on the energy position is particularly difficult. From the core-loss spectra, the sp^2 fraction (sp^2 character/(sp^2 + sp^3 characters)) has been derived and is equal to 87% and 66% for the samples prepared at 973 and 673 K, respectively. The decreased sp^2 character is also confirmed by the low-loss spectra, which show a strong decrease of the π plasmon for the same sample (Figure S1 in Supplementary Information). In addition, the mass density of the nanoplatelets was calculated from the low-loss spectra and is around 1.80 and 1.92 $g.cm^{-3}$ for the samples prepared with a T_{CA} of 973 and 673 K, respectively. These values constitute an intermediate between the values corresponding to glassy carbon and pure graphite (1.44 and 2.27 $g.cm^{-3}$, respectively) [71]. The results obtained via electron diffraction, HRTEM, and EELS analyses are consistent and provide a complete structural and chemical description at the local scale of these samples. During synthesis, the lowest T_{CA} yields nanoplatelets that are mostly disordered and with an O/(C+O) ratio of 12%. On the other hand, the highest T_{CA} yields nanoplatelets that show mostly sp^2 bonding configuration with a short-range crystalline order and an O/(C+O) ratio of 3%. These important chemical and structural modifications should have a strong impact on the electrical properties.

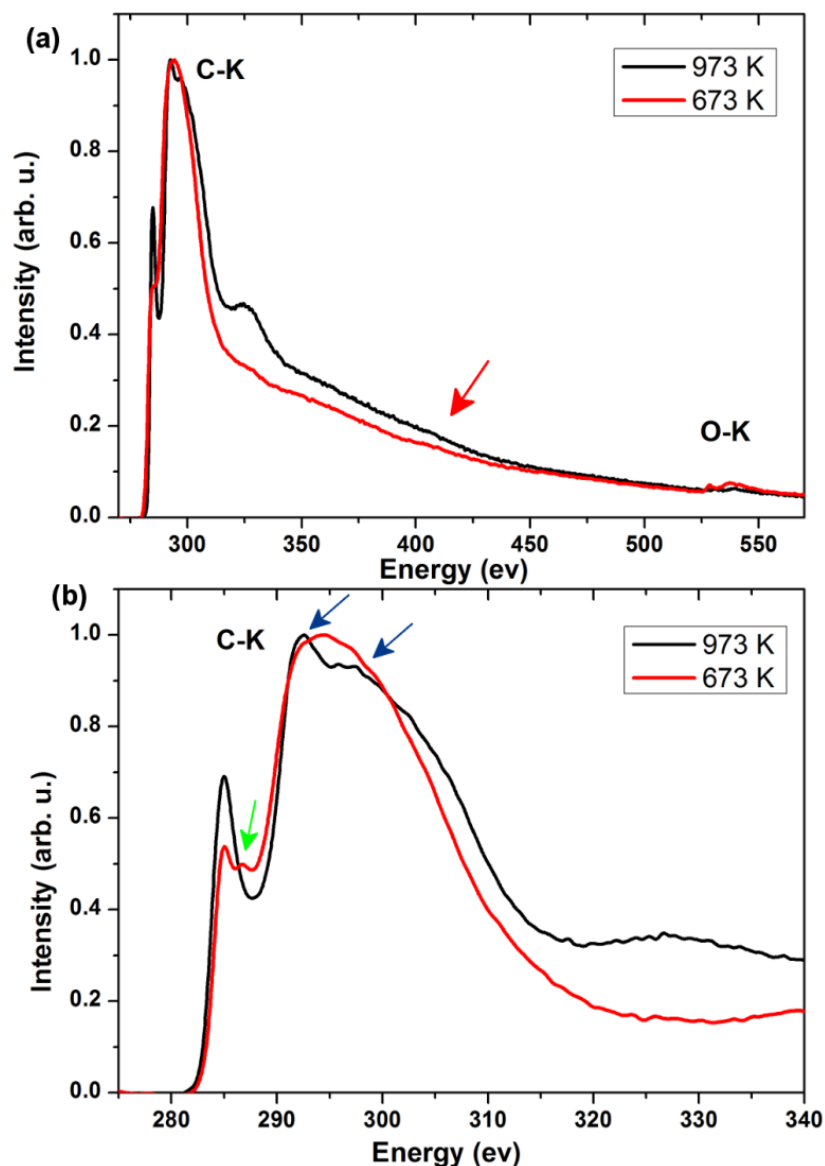


Figure 3. (a) EEL spectra of the samples prepared with a T_{CA} of 973 K (black curve) and 673 K (red curve) and recorded with a dispersion of 0.2 eV/pixel. The red arrow highlights the position of the N-K edge. (b) EEL spectra of the C-K edge recorded with a dispersion of 0.05 eV/pixel. The blue arrows highlight the graphitic fine structures of the sample prepared at 973 K and the green arrow highlights the supplementary peak observed at 286.7 eV for the sample prepared at 673 K (see text for more details). All the spectra have been submitted as references to the EELS database [72].

3.2 Electrical characterization

3.2.1 Room temperature conductivity: Effect of the oxygen content

Variation of synthesis conditions, specifically carbonization temperature, leads to modification of the oxygen-containing functional groups, as well as of the crystal structure in OGNP-BPA, as presented above and also confirmed by X-Ray diffraction (Figure S2 in Supplementary Information) and by other techniques [49]. For electrical characterization we focused on OGNP-BPA obtained at higher T_{CA} (873

and 973 K), which ensures an improved crystal structure, as confirmed by HRTEM (Figure S3 in Supplementary Information). Under these temperature conditions, the oxygen content is below 20%, which is our interest, given that it is known that within this oxygen regime the electrical behavior in GO is still unclear. Room temperature electrical conductivity was obtained via current-voltage (I - V) measurements for the oxygen atomic concentrations $C_O = 5, 8, 13$ and 17%. All I - V curves exhibit ohmic behavior along the entire current range ($\pm 6 \mu\text{A}$), allowing calculation of conductivity values from the slope and geometric parameters of the nanoplatelets obtained via SEM. Room temperature conductivity as a function of C_O is shown in figure 4. Decreased oxygen content from 17 to 5% resulted in conductivity rise by two orders of magnitude, starting from $6.4 \times 10^1 \text{ S/m}$ and reaching a value of $2.3 \times 10^3 \text{ S/m}$ at the lowest oxidation degree. These values are comparable with literature reports on reduced GO obtained through chemical/thermal reduction methods, where it has been shown that conductivity can vary from 5 to $5 \times 10^4 \text{ S/m}$, depending on the degree of reduction [2, 47]. When O atoms from the functional groups are released, the graphene oxide lattice, rich in sp^3 hybridization, transforms to a graphene-like structure due to the restoration of sp^2 hybridization and, thereby, its conductivity increases. Also, rGO sheets, obtained by chemical reduction, exhibit only moderate room-temperature conductivities, predominantly as a consequence of crystal defects (like extended holes) that cannot be healed during the reduction process. Formation of holes in our OGNP-BPA can be considered minimal, as evidenced above by HRTEM examinations.

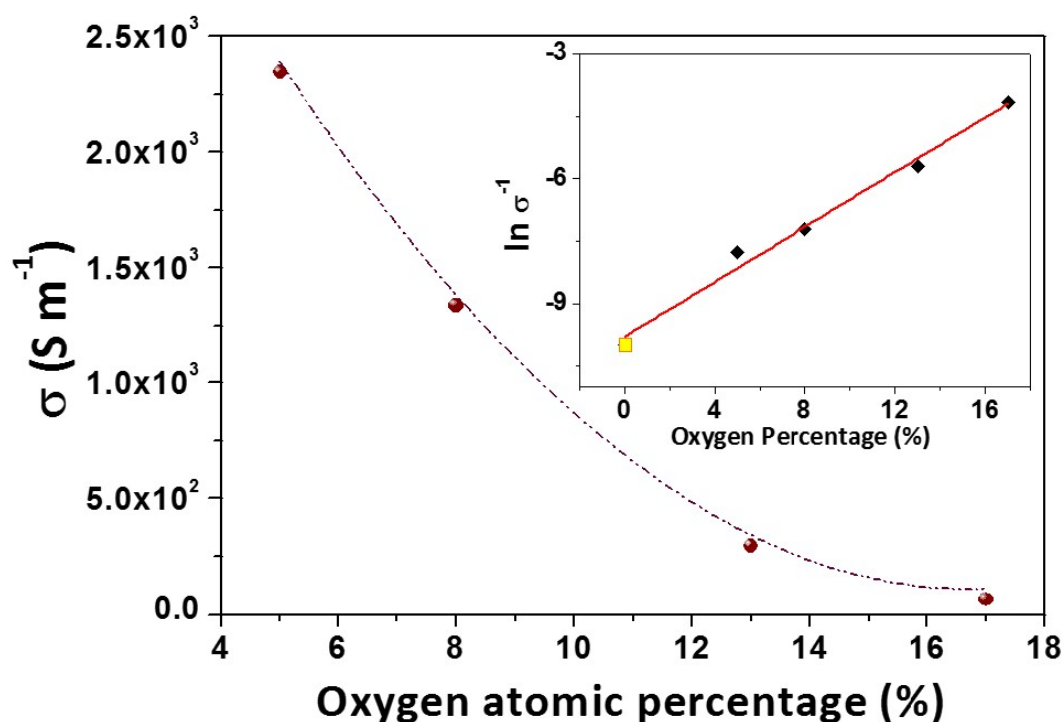


Figure 4. Electrical conductivity as a function of oxygen content ($C_O = 5, 8, 13,$ and 17%). The line is a guide to the eye. Inset: Fit (solid line) to the experimental data (full diamonds) using the expression for carrier concentration for an intrinsic semiconductor.

To gain more insight on the dependence of conductivity on oxygen concentration, shown in figure 4, we consider the relation $\eta \propto \exp\left(-\frac{E_g}{2k_B T}\right)$, which relates the carrier concentration to the temperature and bandgap energy, E_g , for an intrinsic semiconductor; with k_B being the Boltzmann constant. Thus, if a linear dependence of the bandgap on oxygen concentration is assumed, as proposed in [12], and because σ is proportional to η , $\ln(\sigma)$ will behave linearly with C_o . Our experimental data, inset in figure 4, agree well with these theoretical assumptions. For contextualization, we compare our data in this plot with that reported for graphite (yellow square). As can be seen, the conductivity for the lowest value of oxygen content found in OGNP-BPA is still around one order of magnitude lower than the value for graphite ($2 \times 10^4 \text{ Sm}^{-1}$), thereby, elucidating the direct effect of the oxygen functionalized groups on electrical conductivity.

By using the explicit relationship $\sigma = \sigma_0 \exp(-E_g/(2k_B T))$ with $\sigma_0 = 2 \times 10^4 \text{ Sm}^{-1}$, as reported for graphite at $T = 300 \text{ K}$, and considering conductivity values for $C_o = 5, 8, 13,$ and 17% , reported in figure 4, we estimate the energy bandgap values as a function of C_o , as shown in figure 5, along with a fit line using the general quadratic dependence of the bandgap with the scatter center X applied for semiconductors [73, 74]. Bandgap energy shows a variation from 0.30 to 0.11 eV by decreasing the oxygen content. Agreement between our experimental results and theoretical prediction is quite remarkable, providing evidence of oxygen-mediated charge-transport scattering in our OGNP-BPA and suggesting that the OGNP-BPA exhibit narrow-gap semiconductor behavior.

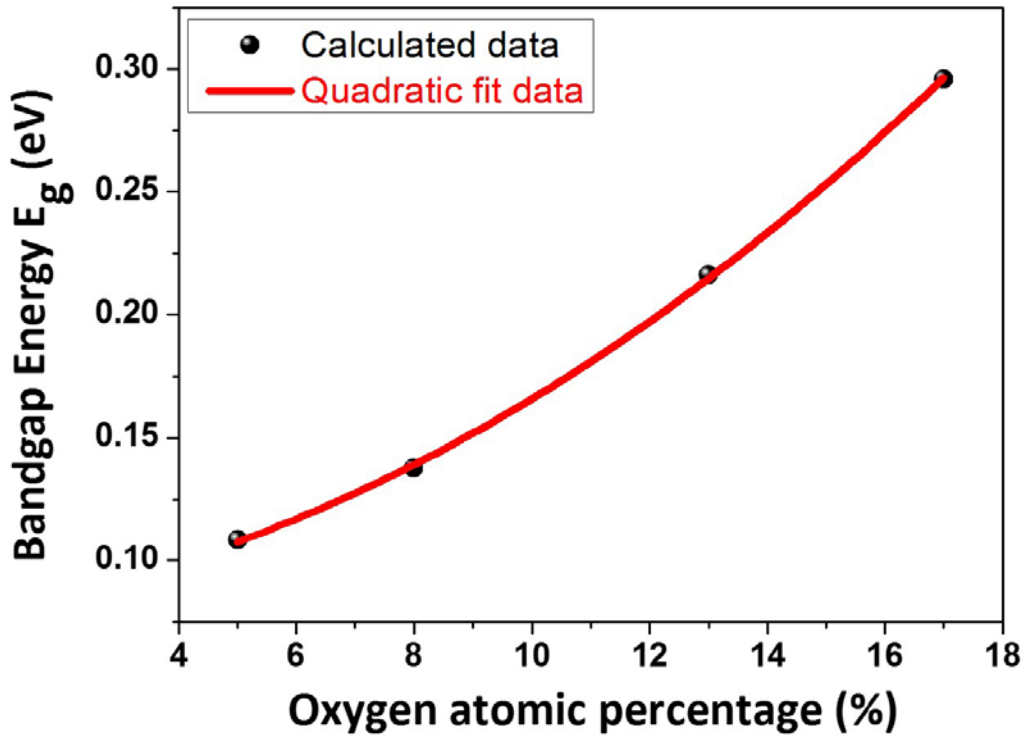


Figure 5. Bandgap (E_g) of OGNP-BPA plotted vs. their corresponding oxygen atomic percentage; red solid line is the fit using the general quadratic dependence of the bandgap with the scatter center X applied for semiconductors [73, 74].

3.2.2 Temperature dependence of electrical conductivity

It has been reported that temperature dependent conductivity in case of semiconductor-like behavior of rGO can be explained by variable-range hopping (VRH) through the localized states [16,?,?]. While in case of electrical conductive system, percolation models are able to fit experimental data [Mutlay and Tudoran]. To gain insight into the energies associated with the charge transport in our OGNP-BPA, the temperature dependence on conductivity is investigated. Figure 6(a) shows the temperature dependence of the resistivity for OGNP-BPA with $C_o = 5\%$. As it can be seen, resistivity increases with decreasing temperature exhibiting a semiconductor-like behavior. The total variation of the resistivity in this range is less than one order of magnitude, showing weak temperature dependence – as reported for highly reduced rGO [47]. We have plotted $\ln(\sigma T^{1/2})$ as a function of $T^{-1/4}$ within 25 – 300 K, which is shown in figure 6(b) along with a best fit line from the VRH model. These results suggest that the charge transport in OGNP-BPA is dominated by the Mott three-dimensional VRH transport behavior. For this case, the temperature dependence on conductivity can be expressed as:

$$\sigma = \frac{\sigma_0}{T^{1/2}} \exp \left[- \left(\frac{T_0}{T} \right)^{1/4} \right] \quad (1)$$

where σ_0 and T_0 are given by:

$$\sigma_0 = \frac{3e^2 \nu_{ph}}{(8\pi)^{1/2}} \times \left[- \left(\frac{N(E_F)}{\alpha k_B} \right) \right]^{1/2} \quad (2)$$

$$T_0 = \frac{16\alpha^3}{k_B N(E_F)} \quad (3)$$

where ν_{ph} is the phonon frequency ($\approx 10^{13}$ Hz) at Debye's temperature. $N(E_F)$ is the density of the localized electron states at Fermi's level and α is the inverse localization length of wave function associated with the localized state. As seen from the graph, $\ln(\sigma T^{1/2})$ versus $T^{-1/4}$ in figure 6(b), the plot exhibits good linear behavior along the entire T range, having a linearity factor of 0.997. From the slope and intercept values, parameters $T_0 = 7.1 \times 10^4$ K and $\sigma_0 = 8.8 \times 10^3$ Sm⁻¹ are obtained. Using the extracted values for T_0 and σ_0 , we calculated the density of the localized states at Fermi's Level $N(E_F) = 1.2 \times 10^{21}$ eV⁻¹cm⁻³ and a value for α of 7.78×10^6 cm⁻¹ according to eq. (2) and (3). Likewise, localization length $\xi = 1/\alpha$ is determined as 1.3 nm. Thus, if assuming a wave function confined inside the graphitic domains of size $D \sim \xi$ and considering the linear dispersion relation for graphene as $E(k) = \hbar \nu_F k$, with ν_F being the graphene Fermi velocity, and with $k \sim 1/2\xi$, the bandgap energy can be estimated as 0.22 ± 0.02 eV, in good agreement with the value of 0.25 eV of oxidized graphene reported elsewhere [75].

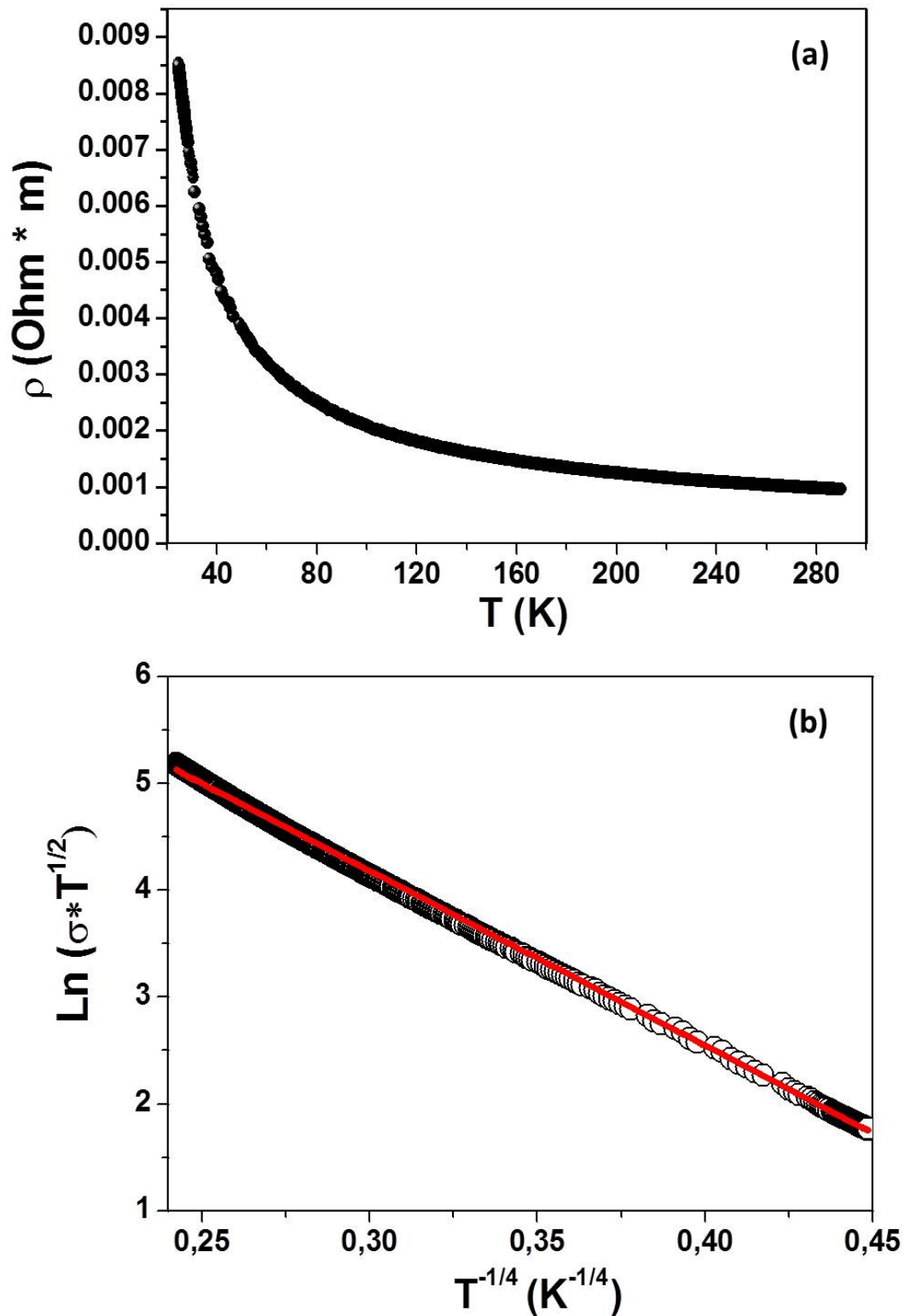


Figure 6. (a) Temperature variation of the resistivity of nanoplatelets with 5% oxygen content. (b) Fit (solid line) to the experimental data (open circles) using the Mott 3D VRH transport model in eq. (1).

4. Conclusions

Oxidized-graphenic nanoplatelets have been synthesized using bamboo (*Guadua angustifolia* Kunth, macana biotype), which is a natural, cheap, highly renewable and abundant material. The HRTEM and EELS analyses have provided a complete structural and chemical description of these samples. We have shown that by varying the carbonization temperature, we can obtain OGNP with oxygen content below 20% and modify their local atomic structure. Nanoplatelets synthesized at the highest temperature of 973 K present lower oxygen content with short-range crystalline order and a carbon environment that is mainly in sp^2 bonding configuration (sp^2 fraction of 87%). On the other hand, nanoplatelets synthesized at the lowest temperature of 673 K present higher oxygen content and have a more disordered crystal structure with a mix of sp^2 and sp^3 characters (sp^2 fraction of 66%). Moreover, we presented the electrical conductivity of single oxidized-graphenic nanoplatelets and investigated the effect of oxygen content via the combination of *in-situ* EDS measurements and electrical measurements. We found an increment by two orders of magnitude of the conductivity, reaching a value of 2.3×10^3 S/m at the lowest oxygen atomic percentage of 5%. The temperature dependence on conductivity showed typical semiconductor behavior, which could be described by the Mott three-dimensional variable-range hopping mechanism (3D-VRH). Estimations of bandgap energy showed variation from 0.30 to 0.11 eV by decreasing oxygen content from 17 to 5%. These results demonstrate that OGNP-BPA possess similar electrical behavior as conventionally obtained rGO sheets, which represents a significant advance towards commercially feasible and environmentally-sustainable fabrication of carbon nanomaterials from renewable natural source.

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